

# UNISONIC TECHNOLOGIES CO., LTD

MGBR20U50 Preliminary DIODE

# MOS GATED BARRIER RECTIFIER

#### DESCRIPTION

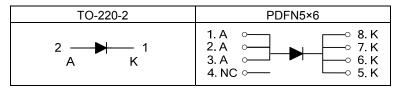
The UTC **MGBR20U50** is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed etc.

The UTC MGBR20U50 suitable for supply applications.

#### ■ FEATURES

- \* Ultra low forward voltage drop
- \* High switching speed

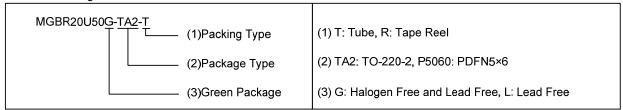
#### SYMBOL



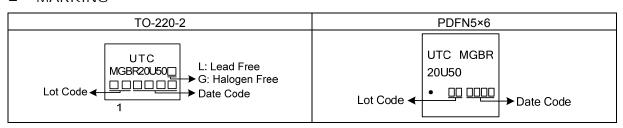
# ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment							Dooking		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing	
MGBR20U50L-TA2-T	MGBR20U50G-TA2-T	TO-220-2	Κ	Α	-	-	-	-	-	-	Tube	
MGBR20U50L-P5060-R	MGBR20U50G-P5060-R	PDFN5×6	Α	Α	Α	NC	Κ	Κ	Κ	Κ	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



## MARKING



1 TO-220-2 PDFN5×6

<u>www.unisonic.com.tw</u> 1 of 3

## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	$V_{RM}$	50	V
Working Peak Reverse Voltage	$V_{RWM}$	50	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	50	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Io	20	Α
Peak Forward Surge Current - 1/2 60hz	I <sub>FSM</sub>	300	Α
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I <sub>RRM</sub>	2	Α
Maximum Rate of Voltage Change ( at Rated V <sub>R</sub> )	dv/dt	10000	V/µS
Operating Junction Temperature	$T_J$	-65 ~ +150	°C
Storage Junction Temperature	T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL DATA

PARAMETER SYMB		SYMBOL	RATINGS	UNIT
lumation to Ameliana	TO-220-2	0	60	, AA
Junction to Ambient	PDFN5×6	ÐJA	72	°C/W

# ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I <sub>R</sub> =0.50mA	50			V
Forward Voltage	V <sub>EM</sub>	I <sub>F</sub> =20A, T <sub>J</sub> =25°C			0.48	V
		I <sub>F</sub> =20A, T <sub>J</sub> =125°C			0.43	V
Reverse Current (Note 1)	DM	V <sub>R</sub> =50V, T <sub>J</sub> =25°C			500	μA
		V <sub>R</sub> =50V, T <sub>J</sub> =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

<sup>2.</sup> Thermal resistance junction to case mounted on heatsink.

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